NSN 5961-01-363-4678

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Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-363-4678 **Inclosure Material:** Plastic **Overall Length:** Between 0.750 inches and 0.785 inches **Overall Height:** 0.200 inches **Overall Width:** Between 0.245 inches and 0.271 inches **Component Name And Quantity:** 16 semiconductor device diode **Mounting Method: Terminal Semiconductor Material:** Silicon single semiconductor device diode Voltage Rating In Volts Per Characteristic: 15.0 forward voltage, dc single semiconductor device diode **Current Rating Per Characteristic:** 200.00 nanoamperes forward current, average peak single semiconductor device diode **Power Rating Per Characteristic:** 650.0 milliwatts forward power dissipation, dc single semiconductor device diode **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Special Features:** Single semiconductor device diode junction pattern arrangement: pn **Terminal Type And Quantity:** 14 printed circuit Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: